



HD29029

Dual CCD Drivers

REJ03D0303-0200Z
 (Previous ADE-205-580 (Z))
 Rev.2.00
 Jul.16.2004

Description

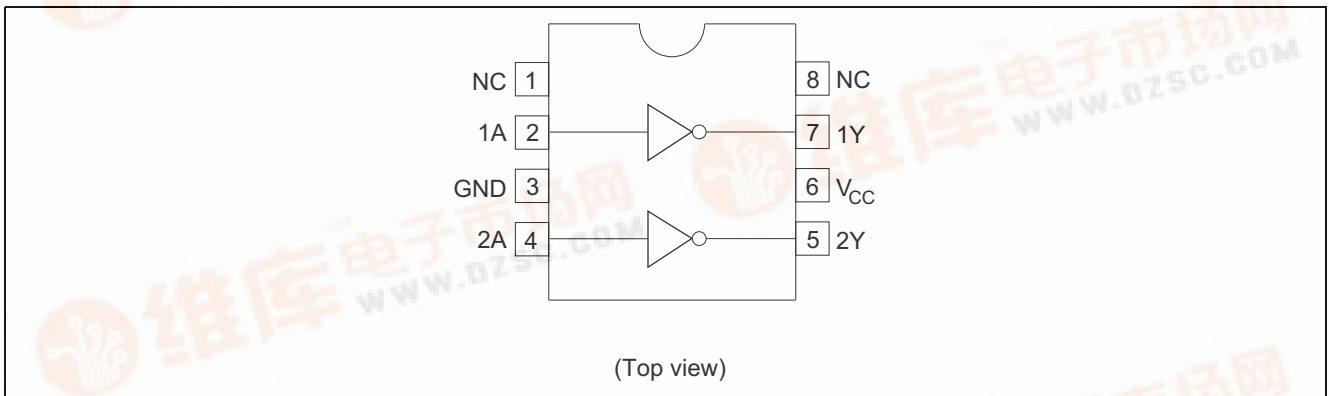
The HD29029 is optimum for CCD drive and has two drivers in a package. The input circuit is operated at TTL level. The outputs are capable of source or sink currents of 0.5 A.

Features

- High-speed operation 7 ns typ in transition times (t_{TLH} , t_{THL}) at $C_L = 200$ pF
- No external components needed because direct drive is available at TTL level inputs
- Output swing voltage: 12 V
- Sink/Source currents: 0.5 A (for each)
- Output cross voltage: 50% typ
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD29029FPEL	SOP-8 pin (JEITA)	FP-8DGV	FP	EL (2,500 pcs/reel)

Pin Arrangement



Function Table

Input A	Output Y
H	L
L	H

H: High level

L: Low level

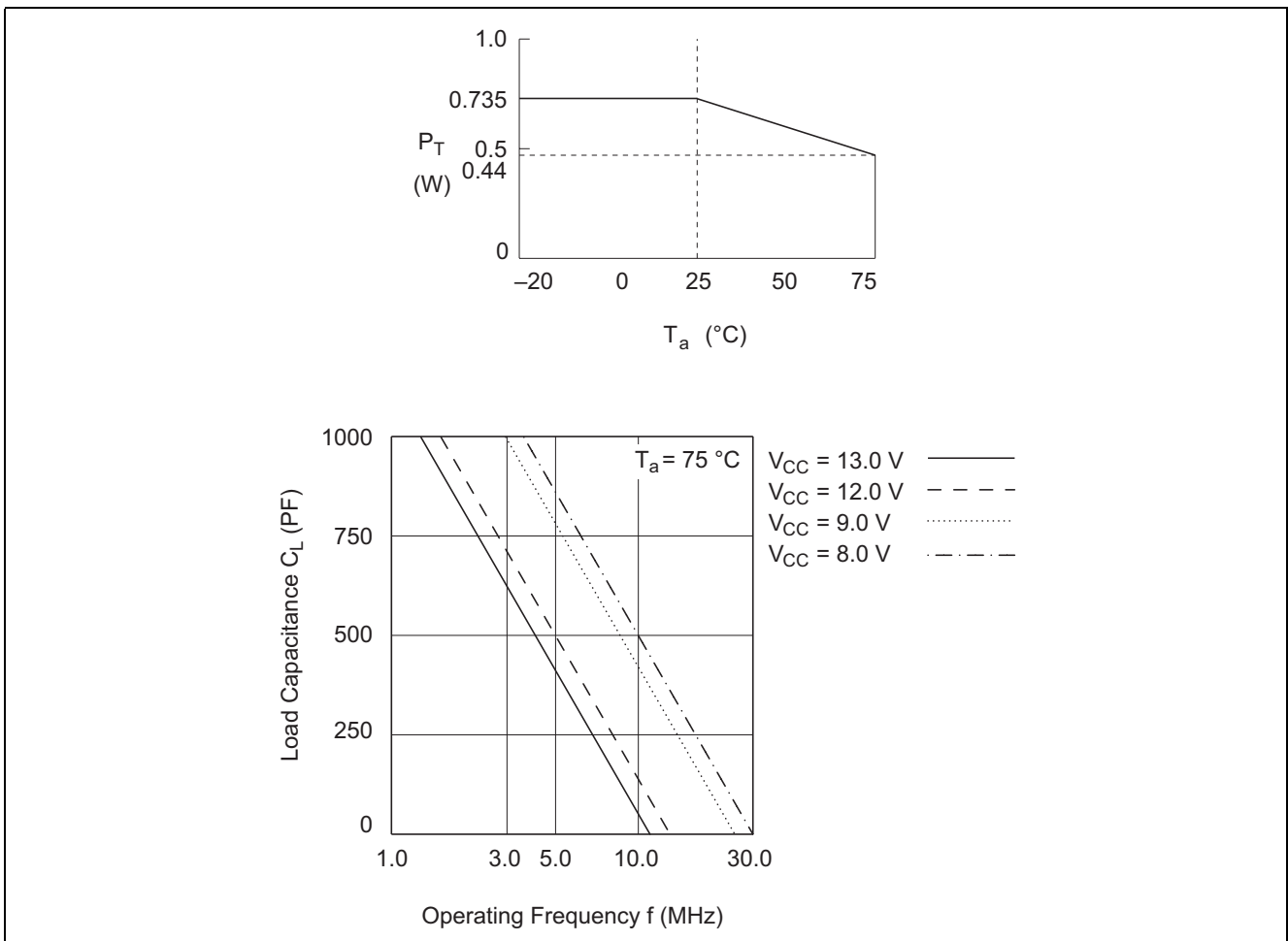
Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply Voltage	V_{CC}^{*1}	15	V
Input Voltage	V_{IN}	7	V
Output Current	$I_{O(peak)}$	± 0.5	A
Operating Temperature	T_a	-20 to +75	$^{\circ}C$
Storage Temperature	T_{stg}	-65 to +150	$^{\circ}C$
Junction Temperature	T_j	150	$^{\circ}C$
Power Dissipation per Package	P_T^{*2}	0.735	W

Notes: 1. The voltage value is defined with respect to ground terminal unless otherwise noted.

2. The total power dissipation is at $T_a = 25^{\circ}C$. When driving large capacity with high frequency radiation is needed. There fore, delating with 5.9 mW/ $^{\circ}C$ must be done as shown below.

3. The absolute maximum ratings are values which must not individually be eceeded, and furthermore, no two of which may be realized at same time.



Recommended Operating Conditions

Item	Symbol	Min	Typ	max	Unit
Supply Voltage	V_{CC}	8.0	9.0	13.0	V
Operating Temperature	T_a	-20	25	75	°C

Electrical Characteristics ($V_{CC} = 8$ to 13 V, $T_a = -20$ to 75°C)

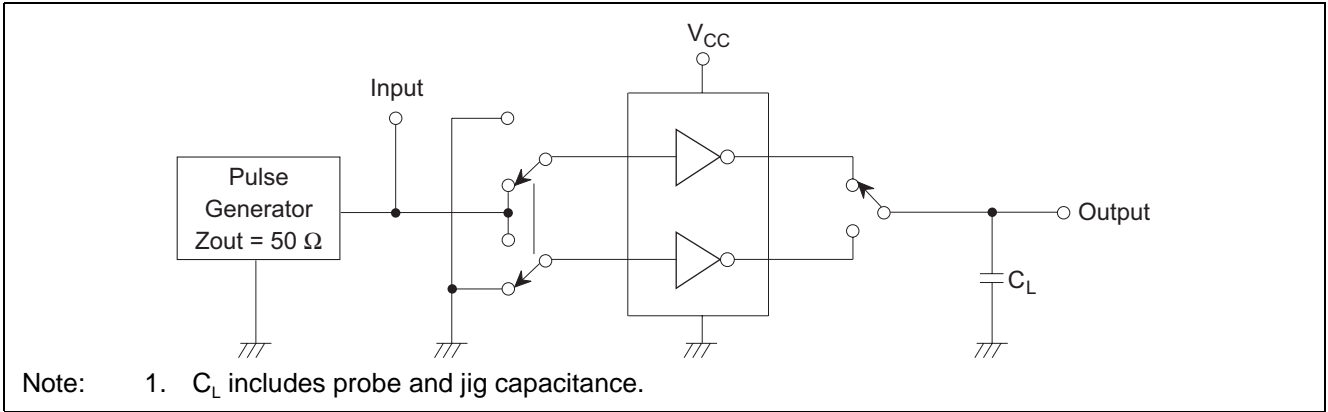
Item	Symbol	Min	Typ	Max	Unit	Conditions
Input Voltage	V_{IH}	2.0	—	—	V	
	V_{IL}	—	—	0.6	V	
Output Voltage	V_{OH}	$V_{CC}-2$	—	—	V	$V_{IL} = 0.6$ V, $I_{OH} = -1$ mA
	V_{OL}	—	—	0.5	V	$V_{IH} = 2.0$ V, $I_{OH} = 1$ mA
Input Current	I_{IH}	—	—	20	μA	$V_I = 2.7$ V
	I_{IL}	—	—	-100	μA	$V_I = 0.4$ V
Supply Current	I_{CCH}	—	—	10	mA	
	I_{CCL}	—	—	25	mA	
Input Current	I_{LI}	—	—	100	μA	$V_I = 7$ V
Input Clamp Voltage	V_{IK}	—	—	-1.5	V	$I_{IN} = -18$ mA

Switching Characteristics ($C_L = 200$ pF, $T_a = 25^\circ\text{C}$)

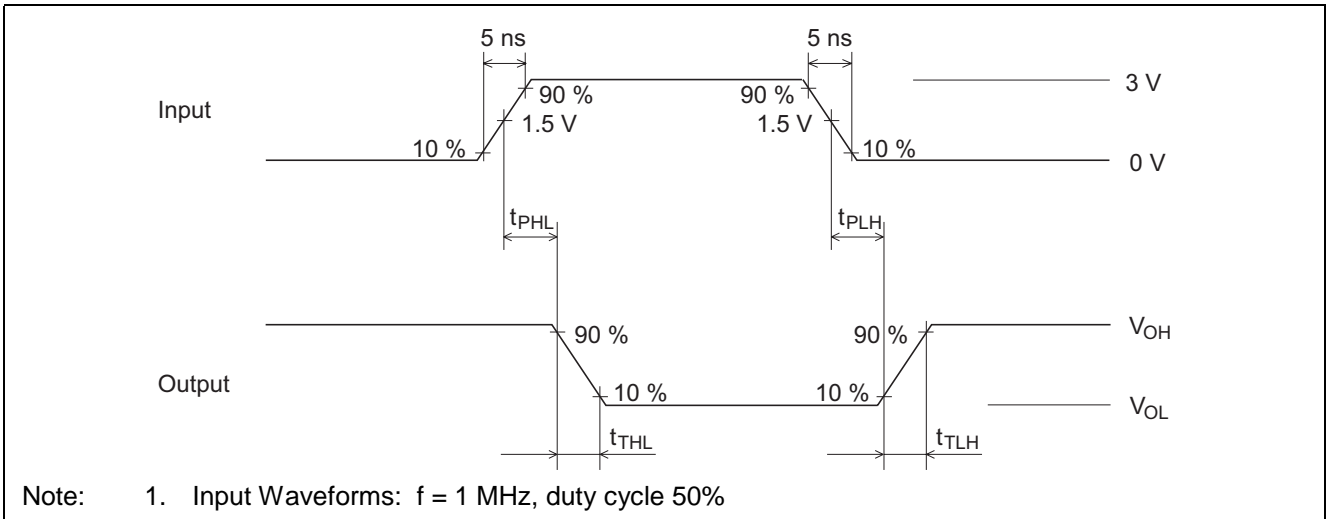
Item	Symbol	Min	Typ	Max	Unit	Conditions
Propagation Delay Time	t_{PHL}	—	4.0	15.0	ns	$V_{CC} = 9$ V
		—	4.0	13.0	ns	$V_{CC} = 12$ V
	t_{PLH}	—	6.0	15.0	ns	$V_{CC} = 9$ V
		—	6.0	13.0	ns	$V_{CC} = 12$ V
Transition Time	t_{THL}	—	8.0	14.0	ns	$V_{CC} = 9$ V
		—	7.0	12.0	ns	$V_{CC} = 12$ V
	t_{TLH}	—	8.0	14.0	ns	$V_{CC} = 9$ V
		—	7.0	12.0	ns	$V_{CC} = 12$ V

Switching Time Test Method

Test circuit



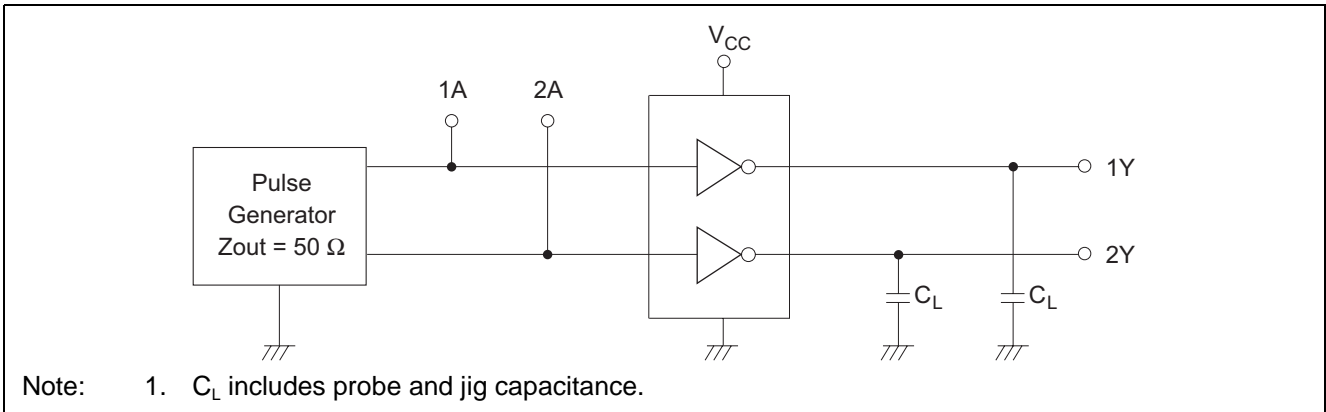
Waveforms



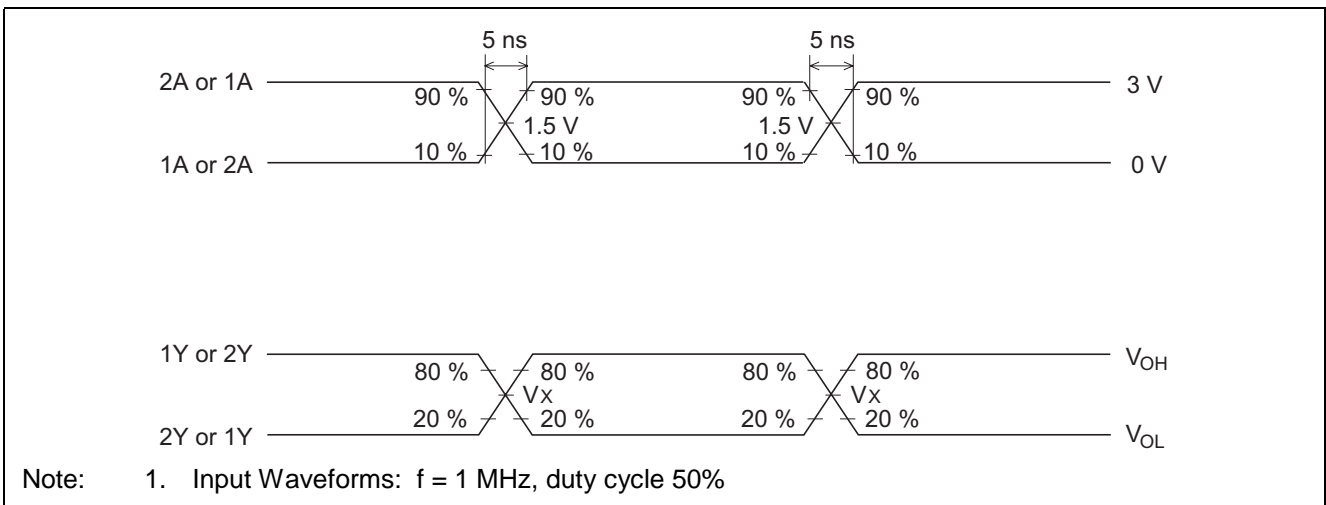
Output Characteristics ($C_L = 200 \text{ pF}$, $T_a = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Conditions
Output Cross Voltage	V_x	20	50	80	%	$V_{CC} = 9 \text{ V}$
		20	50	80	%	$V_{CC} = 12 \text{ V}$

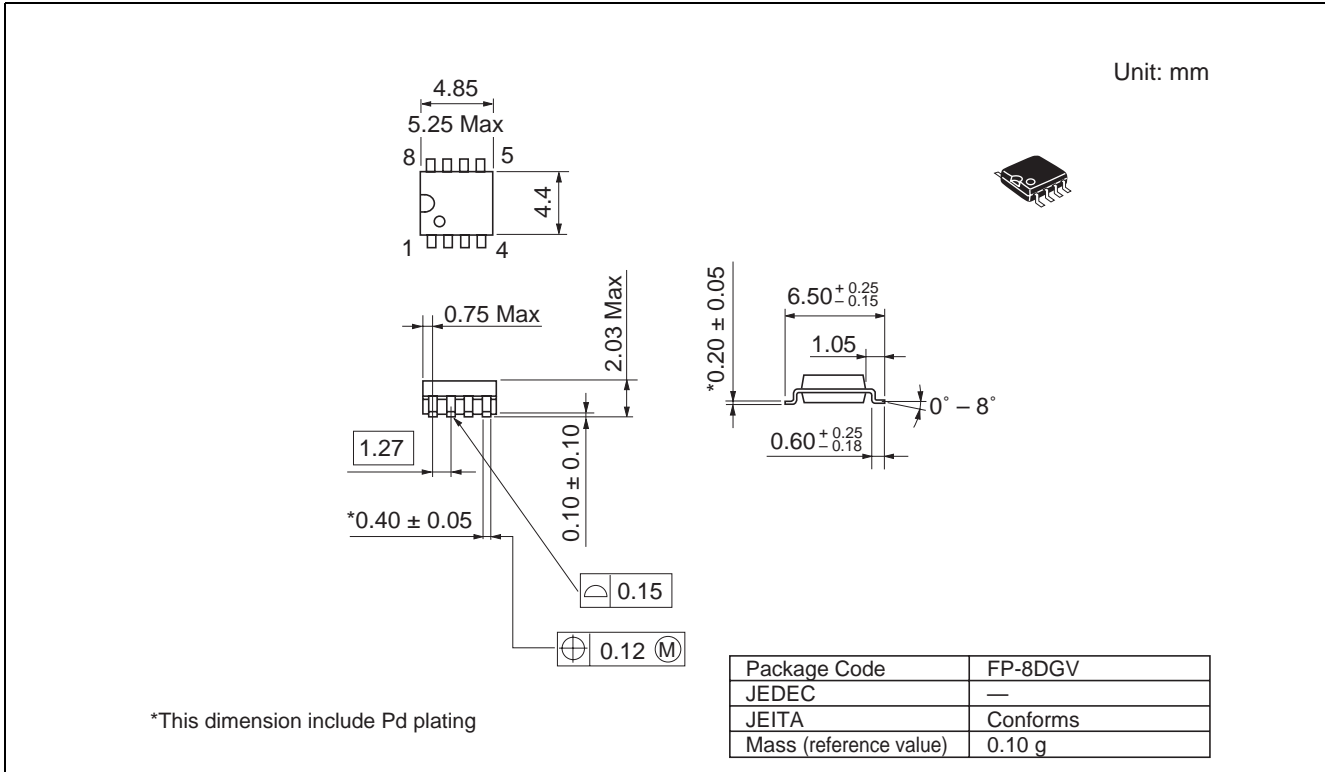
Test circuit



Waveforms



Package Dimensions



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